



LET9120M

RF power transistor from the LdmoST family
of n-channel enhancement-mode lateral MOSFETs

Preliminary data

Features

- Excellent thermal stability
- Common source configuration push-pull
- $P_{OUT} = 120\text{ W}$ with 18 dB gain @ 860 MHz
- Internal input matching
- BeO-free package

Description

The LET9120M is a common source n-channel enhancement-mode lateral field-effect RF power transistor designed for broadband commercial and industrial applications at frequencies up to 1.0 GHz.

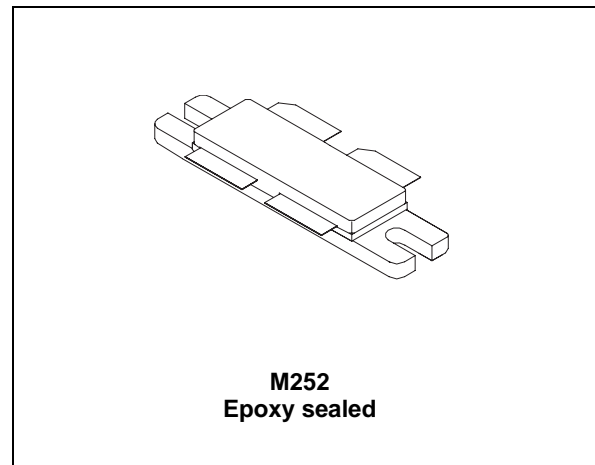
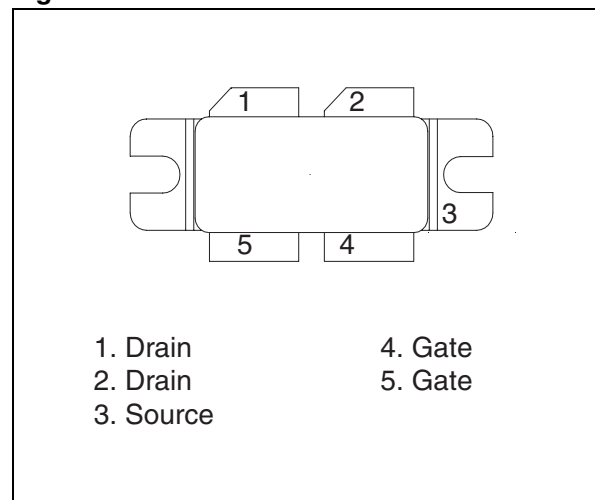


Figure 1. Pin connection



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Table 1. Device summary

Order code	Package	Branding
LET9120M	M252	LET9120M

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1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25\text{ }^{\circ}\text{C}$)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-source voltage	80	V
V_{GS}	Gate-source voltage	± 20	V
I_D	Drain current	18	A
P_{DISS}	Power dissipation (@ $T_c = 70^{\circ}\text{C}$)	217	W
T_J	Max. operating junction temperature	200	$^{\circ}\text{C}$
T_{STG}	Storage temperature	-65 to +150	$^{\circ}\text{C}$

1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Junction - case thermal resistance	0.6	$^{\circ}\text{C}/\text{W}$

2 Electrical characteristics

$$T_{\text{CASE}} = +25\text{ }^{\circ}\text{C}$$

2.1 Static

Table 4. Static (per section)

Symbol	Test conditions		Min	Typ	Max	Unit
$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{ V}$	$I_{\text{DS}} = 1\text{ mA}$	80			V
I_{DSS}	$V_{\text{GS}} = 0\text{ V}$	$V_{\text{DS}} = 28\text{ V}$			1	μA
I_{GSS}	$V_{\text{GS}} = 5\text{ V}$	$V_{\text{DS}} = 0\text{ V}$			1	μA
$V_{\text{GS(Q)}}$	$V_{\text{DS}} = 28\text{ V}$	$I_{\text{D}} = 100\text{ mA}$	2.0		5.0	V
$V_{\text{DS(ON)}}$	$V_{\text{GS}} = 10\text{ V}$	$I_{\text{D}} = 3\text{ A}$		0.9	1.2	V
G_{FS}	$V_{\text{DS}} = 10\text{ V}$	$I_{\text{D}} = 3\text{ A}$	2.5			mho
C_{OSS}	$V_{\text{GS}} = 0\text{ V}$	$V_{\text{DS}} = 28\text{ V}$		29		pF

Note: Device is internally input matched.

2.2 Dynamic

Table 5. Dynamic

Symbol	Test conditions		Min	Typ	Max	Unit
P_{OUT}	$V_{\text{DD}} = 32\text{ V}$	$I_{\text{DQ}} = 400\text{ mA}$ $f = 860\text{ MHz}$	120			W
G_{PS}	$V_{\text{DD}} = 32\text{ V}$	$I_{\text{DQ}} = 400\text{ mA}$ $P_{\text{OUT}} = 120\text{ W}$ $f = 860\text{ MHz}$	16	18	-	dB
η_{D}	$V_{\text{DD}} = 32\text{ V}$	$I_{\text{DQ}} = 400\text{ mA}$ $P_{\text{OUT}} = 120\text{ W}$ $f = 860\text{ MHz}$	50	65		%

3 Package mechanical data

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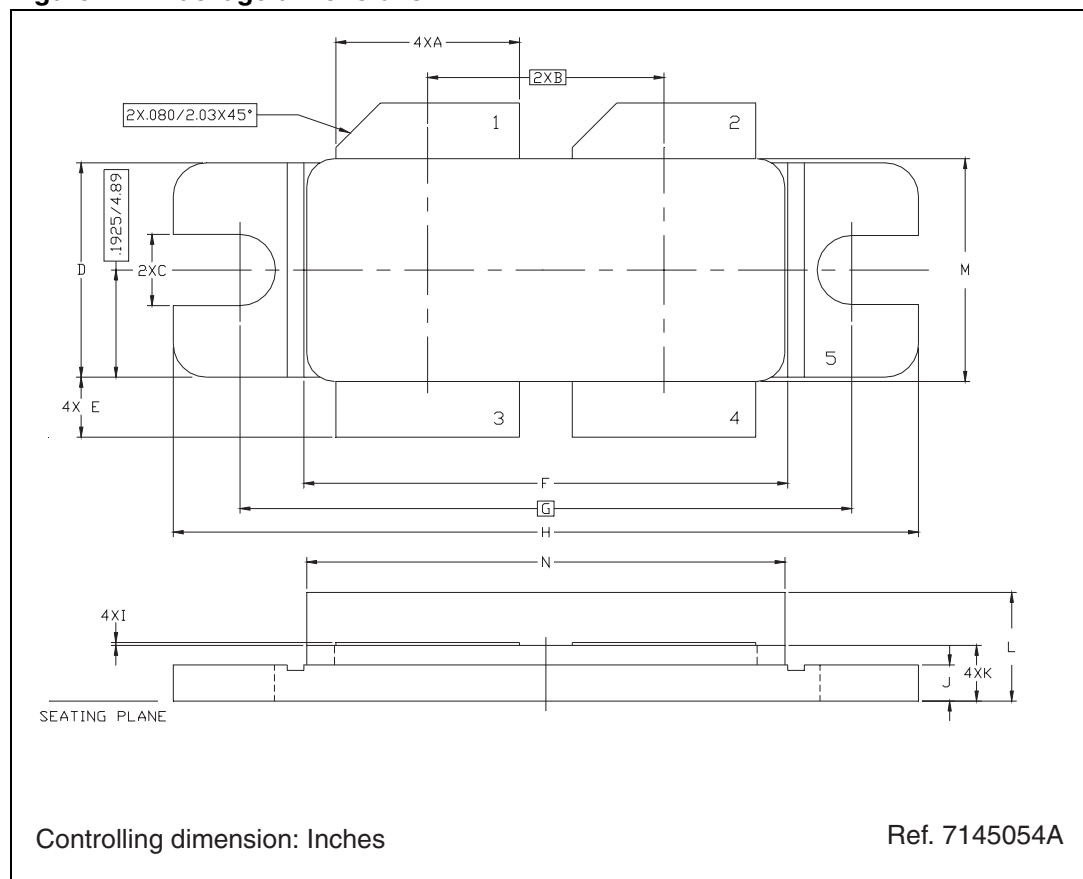
Package mechanical data

LET9120M

Table 6. M252 (.400 x .860 4L BAL N/HERM W/FLG) mechanical data

Dim.	mm.			inch		
	Min	Typ	Max	Min	Typ	Max
A	8.13		8.64	.320		.340
B		10.80			.425	
C	3.00		3.30	.118		.130
D	9.65		9.91	.380		.390
E	2.16		2.92	.085		.115
F	21.97		22.23	.865		.875
G		27.94			1.100	
H	33.91		34.16	1.335		1.345
I	0.10		0.15	.004		.006
J	1.52		1.78	.060		.070
K	2.36		2.74	.093		.108
L	4.57		5.33	.180		.210
M	9.96		10.34	.392		.407
N	21.64		22.05	.852		.868

Figure 2. Package dimensions



4 Revision history

Table 7. Document revision history

Date	Revision	Changes
10-Nov-2009	1	First Issue.

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